

To our customers,

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## Old Company Name in Catalogs and Other Documents

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On April 1<sup>st</sup>, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: <http://www.renesas.com>

April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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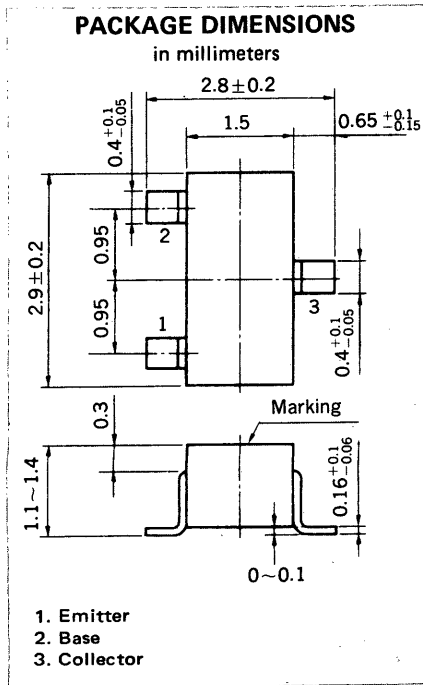
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## FM/AM RF AMPLIFIER, MIXER, OSCILLATOR, CONVERTER NPN SILICON EPITAXIAL TRANSISTOR MINI MOLD



### FEATURES

- High Gain Bandwidth Product:  $f_T = 250$  MHz TYP.
- Low Output Capacitance:  $C_{ob} = 1.8$  pF TYP.
- Low Noise Figure: NF = 2.5 dB TYP.

### ABSOLUTE MAXIMUM RATINGS

Maximum Voltages and Current ( $T_a = 25^\circ\text{C}$ )

Collector to Base Voltage	$V_{CBO}$	50	V
Collector to Emitter Voltage	$V_{CEO}$	30	V
Emitter to Base Voltage	$V_{EBO}$	5.0	V
Collector Current (DC)	$I_C$	50	mA

Maximum Power Dissipation

Total Power Dissipation at $25^\circ\text{C}$ Ambient Temperature	$P_T$	150	mW
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Maximum Temperatures

Junction Temperature	$T_j$	125	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-55 to +125	$^\circ\text{C}$

### ELECTRICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )

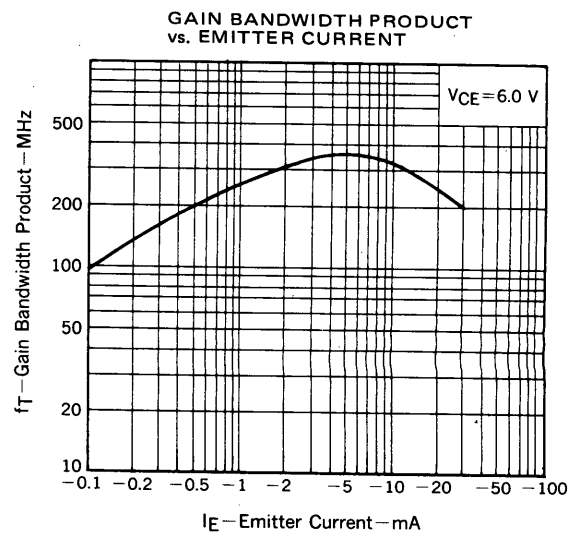
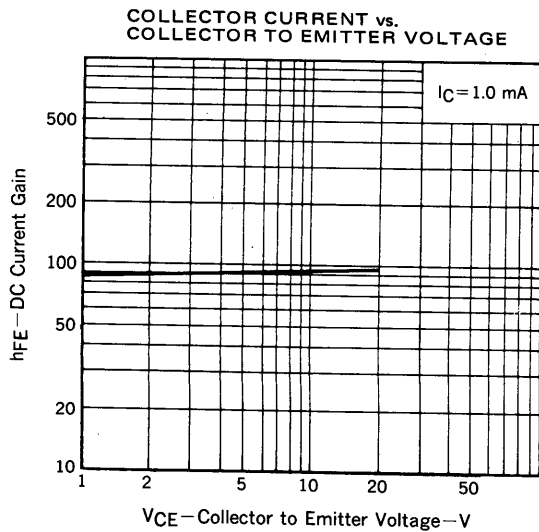
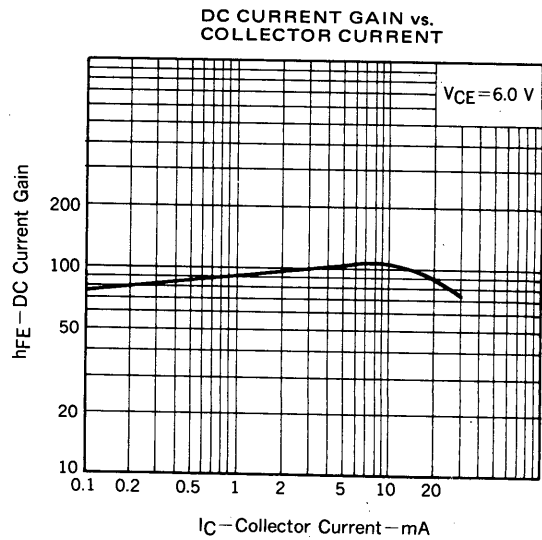
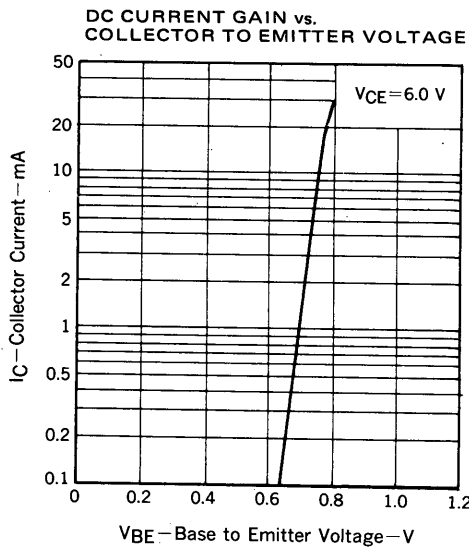
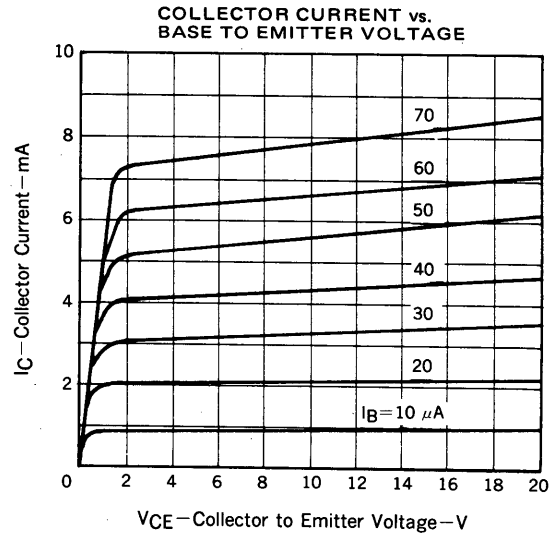
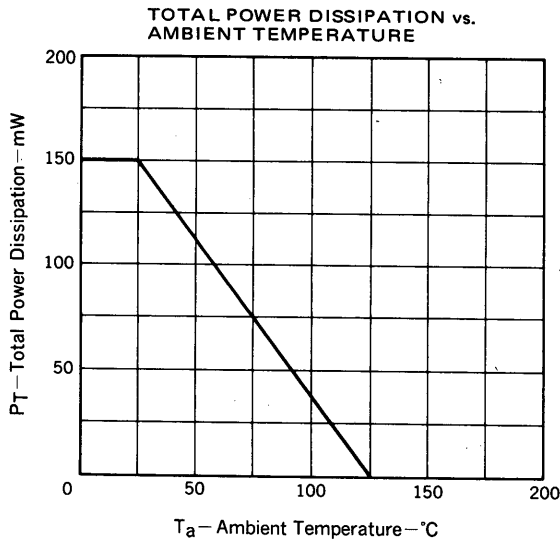
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	$I_{CBO}$			0.1	$\mu\text{A}$	$V_{CB} = 50$ V, $I_E = 0$
Emitter Cutoff Current	$I_{EBO}$			0.1	$\mu\text{A}$	$V_{EB} = 5.0$ V, $I_C = 0$
DC Current Gain	$h_{FE}$	60	100	180		$V_{CE} = 6.0$ V, $I_C = 1.0$ mA*
Base to Emitter Voltage	$V_{BE}$	0.65	0.70	0.75	V	$V_{CE} = 6.0$ V, $I_C = 1.0$ mA
Collector Saturation Voltage	$V_{CE(sat)}$		0.08	0.3	V	$I_C = 10$ mA, $I_B = 1.0$ mA
Gain Bandwidth Product	$f_T$	150	250		MHz	$V_{CE} = 6.0$ V, $I_E = -1.0$ mA
Output Capacitance	$C_{ob}$		1.9	2.2	pF	$V_{CB} = 6.0$ V, $I_E = 0$ , $f = 1.0$ MHz
Collector to Base Time Constant	$C_c \cdot r_b' \cdot b$		10	15	ps	$V_{CB} = 6.0$ V, $I_E = -10$ mA, $f = 31.9$ MHz
Noise Figure	NF		2.0	4.0	dB	$V_{CE} = 6.0$ V, $I_E = -1.0$ mA, $f = 1.0$ MHz, $R_G = 500 \Omega$

\* Pulsed:  $PW \leq 350 \mu\text{s}$ , Duty Cycle  $\leq 2\%$

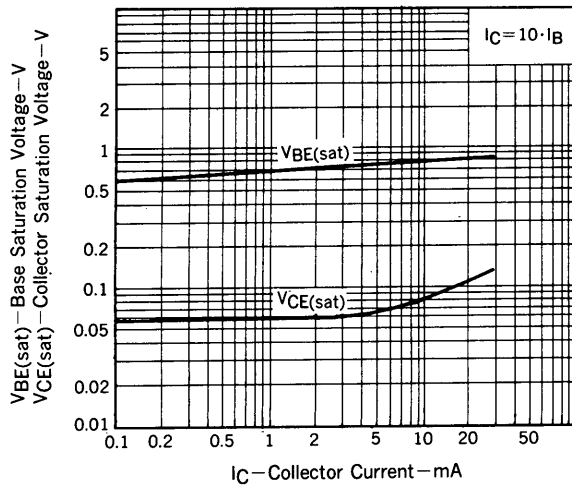
### $h_{FE}$ Classification

Marking	FA3	FA4
$h_{FE}$	60 to 120	90 to 180

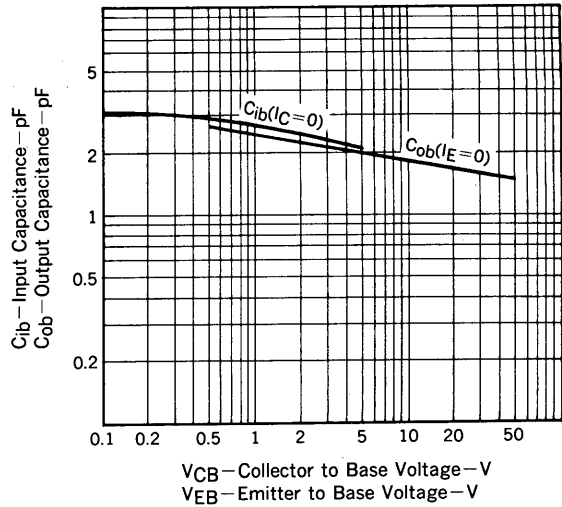
TYPICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )



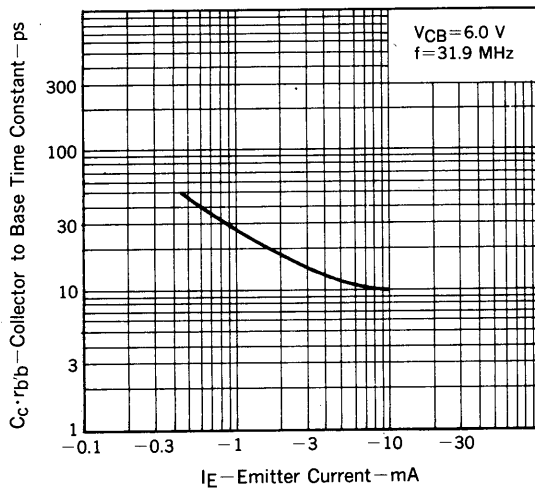
BASE AND COLLECTOR SATURATION VOLTAGE vs. COLLECTOR CURRENT



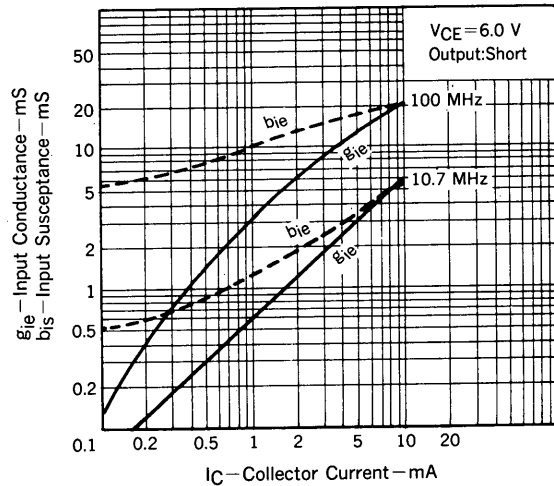
INPUT AND OUTPUT CAPACITANCE vs. REVERSE VOLTAGE



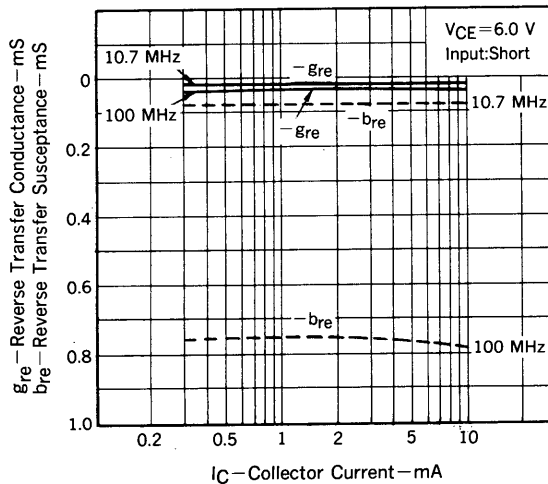
COLLECTOR TO BASE TIME CONSTANT vs. EMITTER CURRENT



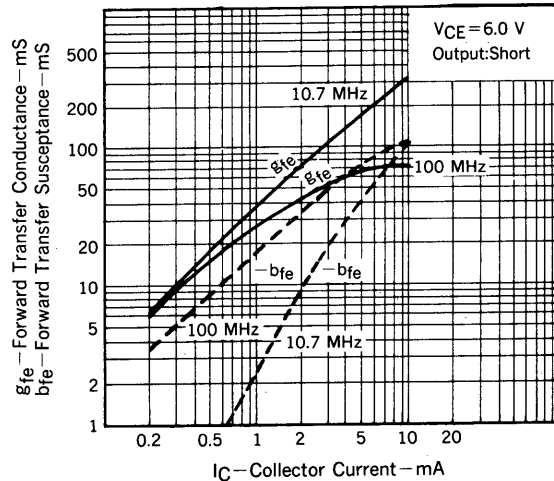
INPUT ADMITTANCE ( $y_{ie}$ ) vs. COLLECTOR CURRENT



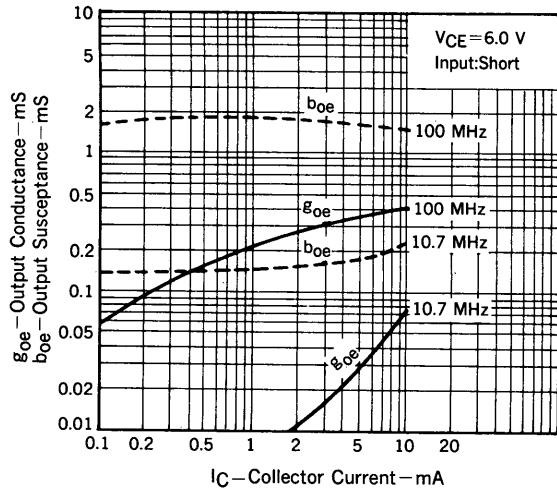
REVERSE TRANSFER ADMITTANCE ( $y_{re}$ ) vs. COLLECTOR CURRENT



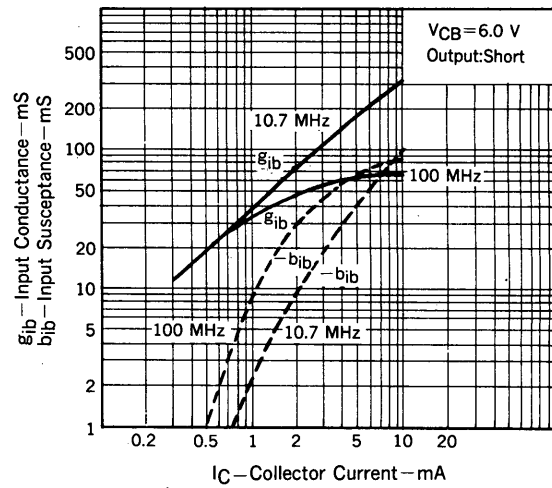
FORWARD TRANSFER ADMITTANCE ( $y_{fe}$ ) vs. COLLECTOR CURRENT



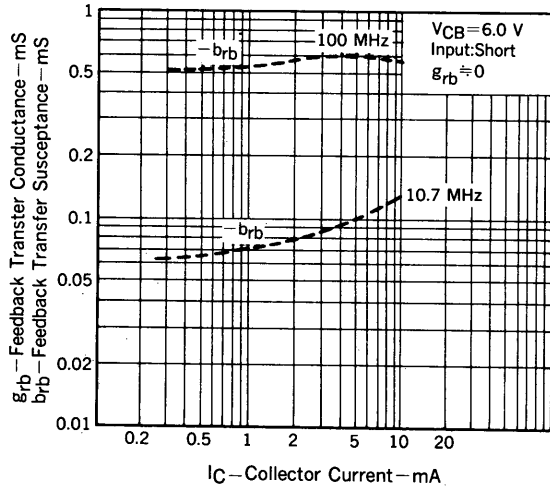
OUTPUT ADMITTANCE ( $y_{oe}$ ) vs. COLLECTOR CURRENT



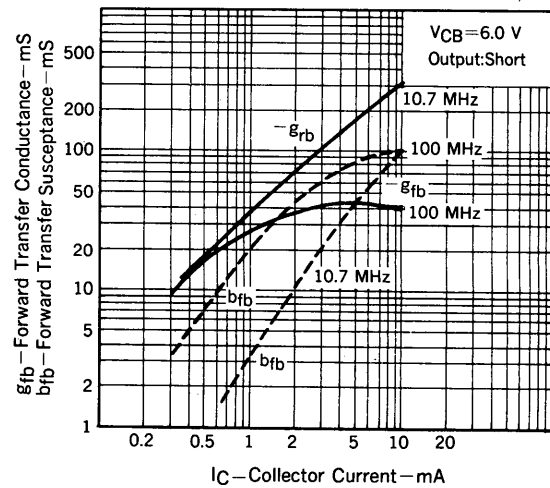
INPUT ADMITTANCE ( $y_{ib}$ ) vs. COLLECTOR CURRENT



REVERSE TRANSFER ADMITTANCE ( $y_{rb}$ ) vs. COLLECTOR CURRENT



FORWARD TRANSFER ADMITTANCE ( $y_{fb}$ ) vs. COLLECTOR CURRENT



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